## **RELIABILITY REPORT**

FOR

#### MAX968ExA

PLASTIC ENCAPSULATED DEVICES

August 3, 2006

## **MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Written by

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#### Conclusion

The MAX968 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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#### I. Device Description

#### A. General

The MAX968 single/dual/quad micropower comparator features Rail-to-Rail inputs and outputs, and fully specified single-supply operation down to +1.6V. This device draws less than  $5\mu$ A per comparator and has open-drain outputs that can be pulled beyond  $V_{CC}$  to 6V (max) above ground. In addition, its rail-to-rail input common-mode voltage range makes this comparator suitable for ultra-low-voltage operation.

A  $\pm 1.6$ V to  $\pm 5.5$ V single-supply operating voltage range makes the MAX968 comparator ideal for 2-cell battery-powered applications. The MAX968 offers programmable hysteresis and an internal 1.235V  $\pm 1.5$ % reference. This device is available in a space-saving 8-pin  $\mu$ MAX package.

# B. Absolute Maximum Ratings Item

Supply Voltage (VCC) +6V
Voltages
IN\_-, IN\_+, REF, HYST -0.3V to (VCC + 0.3V)

Duration of OUT\_ Short Circuit to GND or VCC Continuous Power Dissipation

8-Pin SO (derate 5.88mW/°C above +70°C) 8-Pin µMAX (derate 4.10mW/°C above +70°C)

Operating Temperature Range
Storage Temperature Range

Lead Temperature (soldering, 10s)

-0.3V to +6.0V Continuous

471mW 330mW

Rating

-40°C to +85°C -65°C to +150°C

+300°C

#### **II.** Manufacturing Information

A. Description/Function: Single/Dual/Quad, Micropower, Ultra-Low-Voltage, Rail-to-Rail I/O Comparators

B. Process: B12 (Standard 1.2 micron silicon gate CMOS)

C. Number of Device Transistors: 299

D. Fabrication Location: Oregon, USA

E. Assembly Location: Malaysia, Philippines or Thailand

F. Date of Initial Production: July, 1996

### **III. Packaging Information**

A. Package Type: 8-Pin μMAX 8-Pin SO

B. Lead Frame: Copper Copper

C. Lead Finish: Solder Plate or 100% Matte Tin Solder Plate or 100% Matte Tin

D. Die Attach: Silver-filled Epoxy Silver-filled Epoxy

E. Bondwire: Gold (1 mil dia.) Gold (1 mil dia.)

F. Mold Material: Epoxy with silica filler Epoxy with silica filler

G. Assembly Diagram: # 05-1501-0117 # 05-1501-0116

H. Flammability Rating: Class UL94-V0 Class UL94-V0

I. Classification of Moisture Sensitivity

per JEDEC standard J-STD-020-C: Level 1 Level 1

#### IV. Die Information

A. Dimensions: 50 x 62 mils

B. Passivation: Si<sub>3</sub>N<sub>4</sub>/SiO<sub>2</sub> (Silicon nitride/ Silicon dioxide)

C. Interconnect: Aluminum/Si (Si = 1%)

D. Backside Metallization: None

E. Minimum Metal Width: 1.2 microns (as drawn)

F. Minimum Metal Spacing: 1.2 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.

H. Isolation Dielectric: SiO<sub>2</sub>

I. Die Separation Method: Wafer Saw

#### V. Quality Assurance Information

A. Quality Assurance Contacts: Jim Pedicord (Manager, Reliability Operations)
Bryan Preeshl (Managing Director of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

#### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \text{ x } 4340 \text{ x } 320 \text{ x } 2} \text{ (Chi square value for MTTF upper limit)}$$

$$\lambda = 3.44 \text{ x } 10^{-9}$$

$$\lambda = 3.44 \text{ x } 10^{-9}$$

 $\lambda = 3.44 \text{ F.I.T.}$  (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Attached Burn-In Schematic (Spec. # 06-5241) shows the static Burn-In circuit. Maxim performs failure analysis on any lot that exceeds this reliability control level. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (RR-1N). Current monitor data for the B8/S8 Process results in a FIT rate of 0.10 @ 25°C and 1.78 @ 55°C (eV = 0.8, UCL = 60%).

#### B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard  $85^{\circ}$ C/ $85^{\circ}$ RH testing is done per generic device/package family once a quarter.

#### C. E.S.D. and Latch-Up Testing

The CM32-3 die type has been found to have all pins able to withstand a transient pulse of  $\pm 1500$ V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of  $\pm 250$ mA.

## Table 1 Reliability Evaluation Test Results

## MAX968ExA

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Tes	t (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		320	0
Moisture Testi	ing (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	μMAX SO	77 77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical St	ress (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

#### Attachment #1

TABLE II. Pin combination to be tested. 1/2/

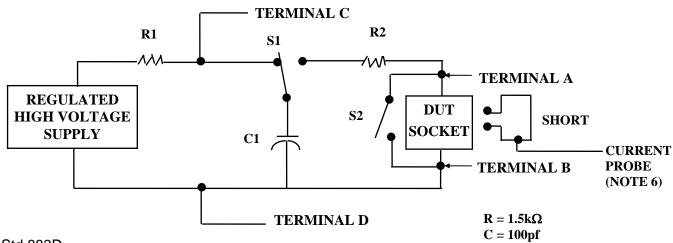
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V <sub>PS1</sub> 3/	All V <sub>PS1</sub> pins
2.	All input and output pins	All other input-output pins

- 1/ Table II is restated in narrative form in 3.4 below.
- No connects are not to be tested.
   Repeat pin combination I for each named Power supply and for ground

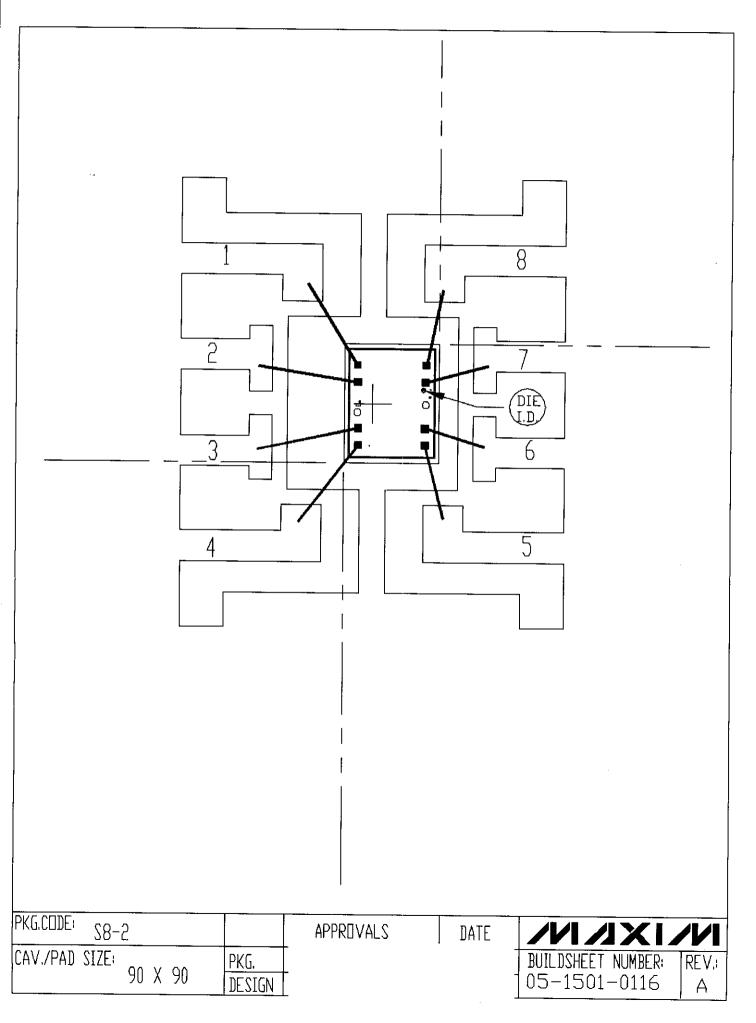
(e.g., where  $V_{PS1}$  is  $V_{DD}$ ,  $V_{CC}$ ,  $V_{SS}$ ,  $V_{BB}$ , GND,  $+V_S$ ,  $-V_S$ ,  $V_{RFF}$ , etc).

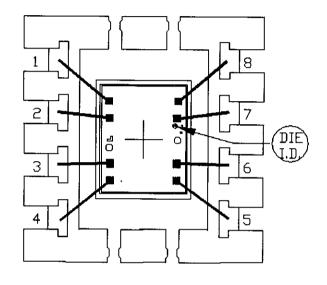
#### 3.4 Pin combinations to be tested.

- Each pin individually connected to terminal A with respect to the device ground pin(s) connected a. to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- Each pin individually connected to terminal A with respect to each different set of a combination b. of all named power supply pins (e.g., V<sub>SS1</sub>, or V<sub>SS2</sub> or V<sub>SS3</sub> or V<sub>CC1</sub>, or V<sub>CC2</sub>) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- Each input and each output individually connected to terminal A with respect to a combination of C. all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



Mil Std 883D Method 3015.7 Notice 8





PKG.CODE: U8-1		APPROVALS	DATF	NIXIXI	/VI
CAV./PAD SIZE:	PKG.			BUILDSHEET NUMBER:	REV.:
68X94	DESIGN		_	05-1501-0117	A

